Amendments to the Specification:

Please replace the paragraph beginning on page 4, line 1, with the following amended paragraph:

The invention will be explained by means of example, wherein

Figure 1 shows a BAW resonator with a roughened rear side of the substrate,

Figure 2 shows an absorbing layer that is disposed onto the rear side of the substrate.

Figure 3 shows an absorbing layer that is disposed onto the front side of the substrate and below a Bragg reflector,

Figure 4 shows a bulk resonator's frequency response of a 2.79 GHz BAW filter which comprises some of the above mentioned means for suppression of the band-pass ripple. ripple,

Figure 5 shows one embodiment of a ladder configuration of a plurality of the BAW resonators of any of Figures 1, 2, or 3,

Figure 6 shows one embodiment of a lattice configuration of a plurality of the BAW resonators of any of Figures 1, 2, or 3.

Please add the following paragraphs immediately before the paragraph beginning on page 5, line 30:

Figure 5 shows one embodiment of a ladder configuration 10 of a plurality of the BAW resonators 12 of any of Figures 1, 2, or 3. The illustrated BAW resonators 12 are representative of any one type, or a combination of types, of the BAW resonators described herein. In particular, the illustrated ladder configuration 10 includes two BAW resonators 12 coupled in series, and a third BAW resonator 12 coupled as a shunt resonator. Although Figure 5 shows one embodiment of a particular ladder configuration 10 of the BAW resonators 12, other embodiments may include fewer or more resonators 12 in a similar or different configuration.

Figure 6 shows one embodiment of a lattice configuration 20 of a plurality of the BAW resonators 12 of any of Figures 1, 2, or 3. The illustrated BAW resonators 12 are representative of any one type, or a combination of types, of the BAW resonators described herein. In particular, the illustrated lattice configuration 20 includes two BAW resonators 12 coupled as two separate series resonators, and two other BAW resonator 12 coupled as a shunt resonators in a crisscross fashion. Although Figure 6 shows one embodiment of a particular lattice configuration 20 of the BAW resonators 12, other embodiments may include fewer or more resonators 12 in a similar or different configuration.